



MMBTA55 / MMBTA56

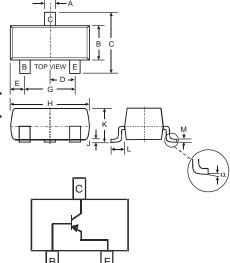
PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (MMBTA05 / MMBTA06)
- Ideal for Low Power Amplification and Switching
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 3 and 4)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020d
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- MMBTA55 Marking (See Page 3): K2H, K2G
- MMBTA56 Marking (See Page 3): K2G
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)



SOT-23									
Dim	Min	Max							
Α	0.37	0.51							
В	1.20	1.40							
С	2.30	2.50							
D	0.89	1.03							
Е	0.45	0.60							
G	1.78	2.05							
Н	2.80	3.00							
J	0.013	0.10							
К	0.903	1.10							
L	0.45	0.61							
м	0.085	0.180							
α	0°	8°							
All Dir	nensions	in mm							

Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	MMBTA55	MMBTA56	Unit	
Collector-Base Voltage	V _{CBO}	-60	-80	V	
Collector-Emitter Voltage	V _{CEO}	-60	-80	V	
Emitter-Base Voltage	V _{EBO}	-4	V		
Collector Current - Continuous (Note 1)	lc	-5	mA		
Power Dissipation (Note 1)	Pd	30	mW		
Thermal Resistance, Junction to Ambient (Note 1)	R _{0JA}	4	°C/W		
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to	°C		

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Min	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 2)					1			
Collector-Base Breakdown Voltage	MMBTA55 MMBTA56	V _(BR) CBO	-60 -80	_	V	$I_{\rm C} = -100 \mu A, I_{\rm E} = 0$		
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-60 -80	_	V	I _C = -1.0mA, I _B = 0			
Emitter-Base Breakdown Voltage		V _{(BR)EBO}	-4.0		V	$I_E = -100 \mu A$, $I_C = 0$		
Collector Cutoff Current	MMBTA55 MMBTA56	I _{CBO}	_	-100	nA	$V_{CB} = -60V, I_E = 0$ $V_{CB} = -80V, I_E = 0$		
Collector Cutoff Current MMBTA55 MMBTA56		ICEX	_	-100	nA	$V_{CE} = -60V, I_{BO} = 0V$ $V_{CE} = -80V, I_{BO} = 0V$		
ON CHARACTERISTICS (Note 2)								
DC Current Gain		h _{FE}	100	—	_	$I_{C} = -10 \text{mA}, V_{CE} = -1.0 \text{V}$ $I_{C} = -100 \text{mA}, V_{CE} = -1.0 \text{V}$		
Collector-Emitter Saturation Voltage		V _{CE(SAT)}		-0.25	V	I _C = -100mA, I _B = -10mA		
Base-Emitter Saturation Voltage		V _{BE(SAT)}	_	-1.2	V	$I_{C} = -100 \text{mA}, V_{CE} = -1.0 \text{V}$		
SMALL SIGNAL CHARACTERISTICS				-	•	-		
Current Gain-Bandwidth Product		f⊤	50	_	MHz	V _{CE} = -1.0V, I _C = -100mA, f = 100MHz		

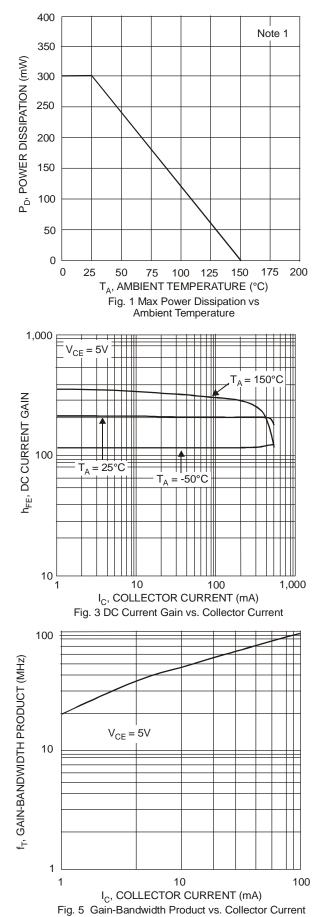
Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

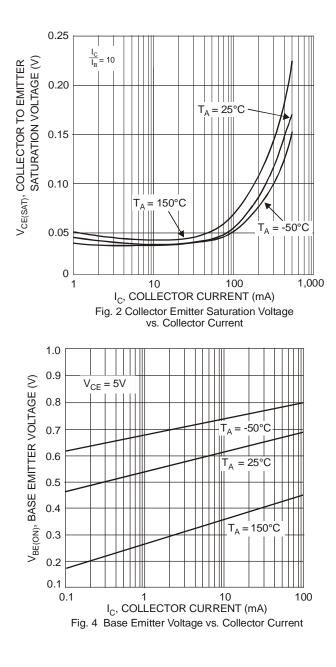
2. Short duration pulse test used to minimize self-heating effect.

3. No purposefully added lead. Halogen and Antimony Free.

Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.







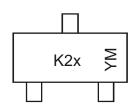


Ordering Information (Note 5)

Device	Packaging	Shipping			
MMBTA55-7-F	SOT-23	3000/Tape & Reel			
MMBTA56-7-F	SOT-23	3000/Tape & Reel			

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K2x = Product Type Marking Code, ex: K2H = MMBTA55 YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	к	L	М	Ν	Р	R	S	Т	U	V	W	Х	Y	Z
Month	Jan	Fe	b I	Mar	Apr	May	Ju	n	Jul	Aug	Sep	Oc	t I	Nov	Dec
Code	1	2		3	4	5	6		7	8	9	0		Ν	D

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